

## Standard Rectifier Module

$$V_{RRM} = 2 \times 1200 \text{ V}$$

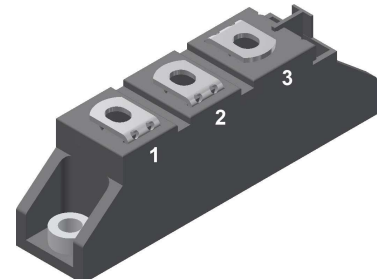
$$I_{FAV} = 140 \text{ A}$$

$$V_F = 1.11 \text{ V}$$

Phase leg

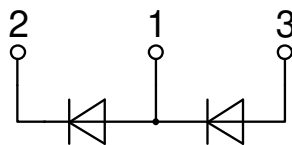
Part number

**MDMA140P1200TG**



Backside: isolated

 E72873



### Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

### Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Height: 30 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

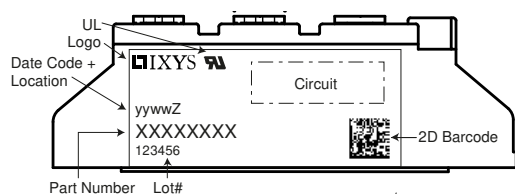
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| Rectifier  |                                              |                                                      |                                | Ratings                        |      |      |                   |
|------------|----------------------------------------------|------------------------------------------------------|--------------------------------|--------------------------------|------|------|-------------------|
| Symbol     | Definition                                   | Conditions                                           |                                | min.                           | typ. | max. | Unit              |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$                        |                                |                                |      | 1300 | V                 |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$                        |                                |                                |      | 1200 | V                 |
| $I_R$      | reverse current                              | $V_R = 1200\text{ V}$                                | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 100  | $\mu\text{A}$     |
|            |                                              | $V_R = 1200\text{ V}$                                | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 3.5  | mA                |
| $V_F$      | forward voltage drop                         | $I_F = 140\text{ A}$                                 | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 1.18 | V                 |
|            |                                              | $I_F = 280\text{ A}$                                 |                                |                                |      | 1.43 | V                 |
|            |                                              | $I_F = 140\text{ A}$                                 | $T_{VJ} = 125^{\circ}\text{C}$ |                                |      | 1.11 | V                 |
|            |                                              | $I_F = 280\text{ A}$                                 |                                |                                |      | 1.41 | V                 |
| $I_{FAV}$  | average forward current                      | $T_C = 100^{\circ}\text{C}$<br>rectangular $d = 0.5$ | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 140  | A                 |
| $V_{F0}$   | threshold voltage                            | } for power loss calculation only                    |                                | $T_{VJ} = 150^{\circ}\text{C}$ |      | 0.78 | V                 |
| $r_F$      | slope resistance                             |                                                      |                                |                                |      | 2.2  | m $\Omega$        |
| $R_{thJC}$ | thermal resistance junction to case          |                                                      |                                |                                |      | 0.23 | K/W               |
| $R_{thCH}$ | thermal resistance case to heatsink          |                                                      |                                |                                | 0.2  |      | K/W               |
| $P_{tot}$  | total power dissipation                      | $T_C = 25^{\circ}\text{C}$                           |                                |                                |      | 540  | W                 |
| $I_{FSM}$  | max. forward surge current                   | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$     | $T_{VJ} = 45^{\circ}\text{C}$  |                                |      | 2.80 | kA                |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$    | $V_R = 0\text{ V}$             |                                |      | 3.03 | kA                |
|            |                                              | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$     | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 2.38 | kA                |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$    | $V_R = 0\text{ V}$             |                                |      | 2.57 | kA                |
| $I^2t$     | value for fusing                             | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$     | $T_{VJ} = 45^{\circ}\text{C}$  |                                |      | 39.2 | kA <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$    | $V_R = 0\text{ V}$             |                                |      | 38.1 | kA <sup>2</sup> s |
|            |                                              | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$     | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 28.3 | kA <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$    | $V_R = 0\text{ V}$             |                                |      | 27.5 | kA <sup>2</sup> s |
| $C_J$      | junction capacitance                         | $V_R = 400\text{ V}; f = 1\text{ MHz}$               |                                |                                | 116  |      | pF                |



| Package TO-240AA |                                                              |                      |                                     | Ratings |      |      |      |
|------------------|--------------------------------------------------------------|----------------------|-------------------------------------|---------|------|------|------|
| Symbol           | Definition                                                   | Conditions           |                                     | min.    | typ. | max. | Unit |
| $I_{RMS}$        | RMS current                                                  | per terminal         |                                     |         |      | 200  | A    |
| $T_{VJ}$         | virtual junction temperature                                 |                      |                                     | -40     |      | 150  | °C   |
| $T_{op}$         | operation temperature                                        |                      |                                     | -40     |      | 125  | °C   |
| $T_{stg}$        | storage temperature                                          |                      |                                     | -40     |      | 125  | °C   |
| <b>Weight</b>    |                                                              |                      |                                     |         | 76   |      | g    |
| $M_D$            | mounting torque                                              |                      |                                     | 2.5     |      | 4    | Nm   |
| $M_T$            | terminal torque                                              |                      |                                     | 2.5     |      | 4    | Nm   |
| $d_{Spp/Apb}$    | creepage distance on surface   striking distance through air | terminal to terminal | 13.0                                | 9.7     |      |      | mm   |
| $d_{Spb/Apb}$    |                                                              | terminal to backside | 16.0                                | 16.0    |      |      | mm   |
| $V_{ISOL}$       | isolation voltage                                            | t = 1 second         | 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA | 4800    |      |      | V    |
|                  |                                                              | t = 1 minute         |                                     | 4000    |      |      | V    |



#### Part description

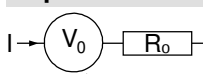
M = Module  
 D = Diode  
 M = Standard Rectifier  
 A = (up to 1800V)  
 140 = Current Rating [A]  
 P = Phase leg  
 1200 = Reverse Voltage [V]  
 TG = TO-240AA

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | MDMA140P1200TG  | MDMA140P1200TG     | Box           | 36       | 512703   |

#### Equivalent Circuits for Simulation

\* on die level

$T_{VJ} = 150^{\circ}\text{C}$



Rectifier

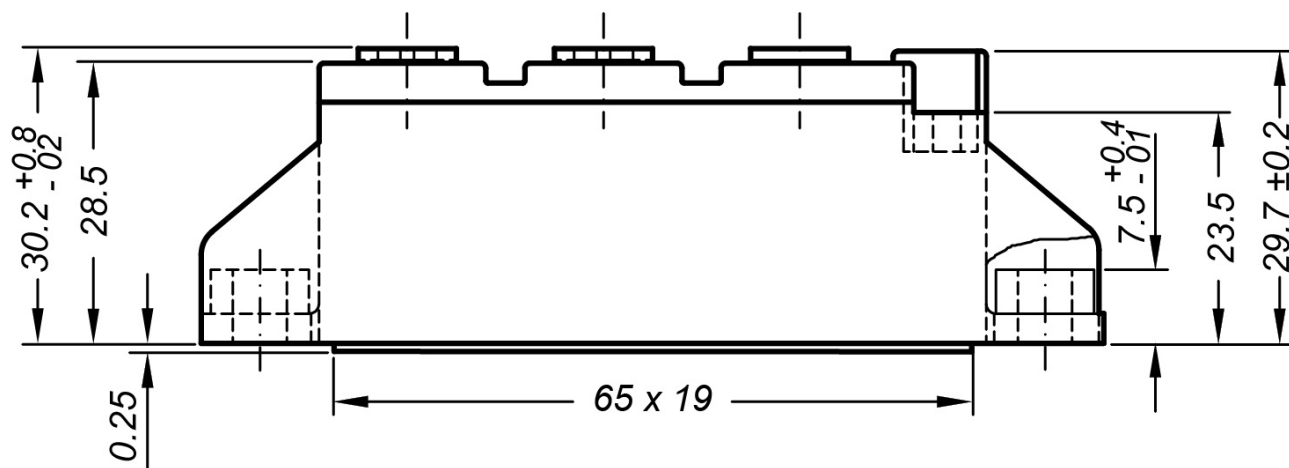
$V_{0\max}$  threshold voltage 0.78

V

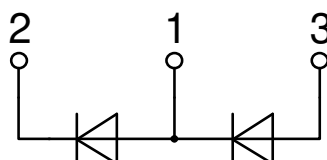
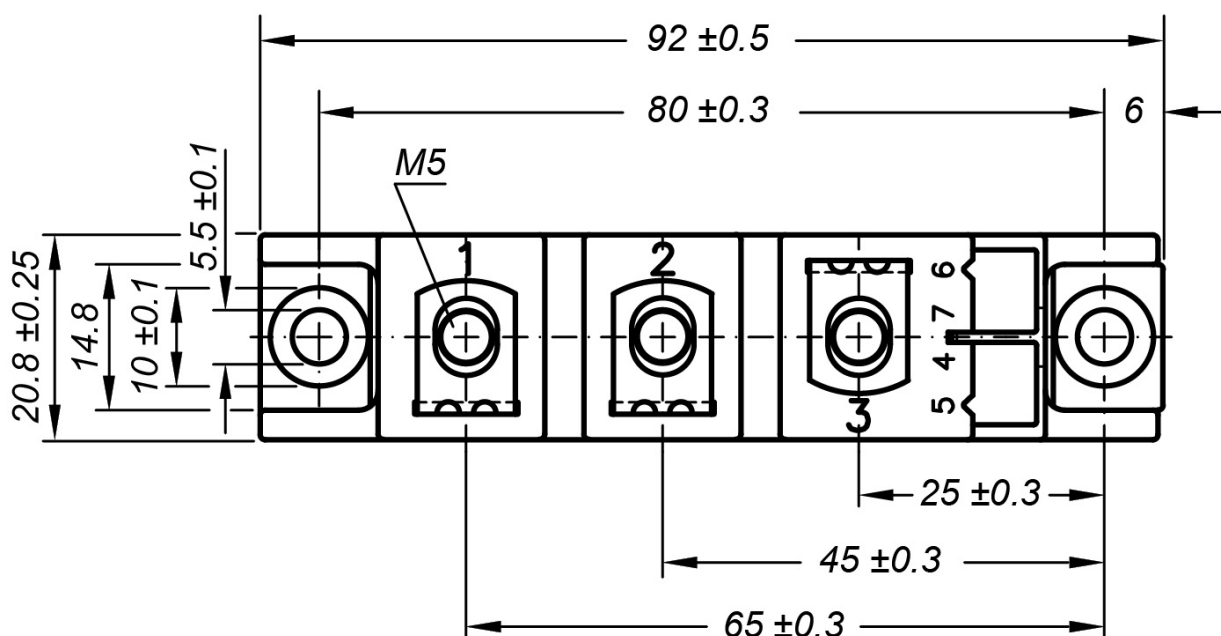
$R_{0\max}$  slope resistance \* 1

mΩ

## Outlines TO-240AA



*General tolerance: DIN ISO 2768 class „c“*



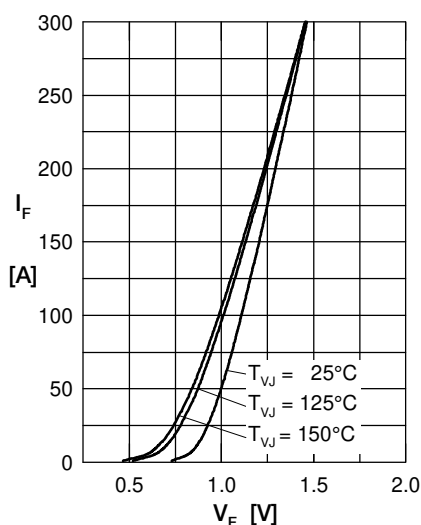
**Rectifier**


Fig. 1 Forward current versus voltage drop per diode

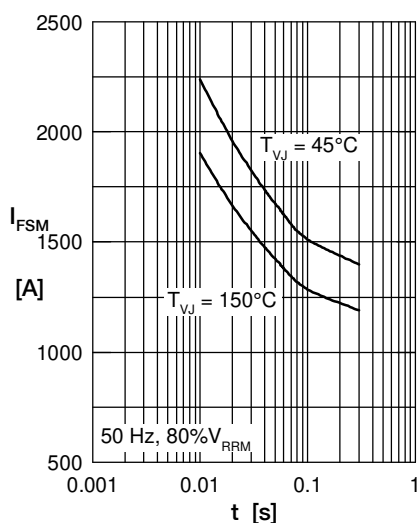


Fig. 2 Surge overload current vs. time per diode

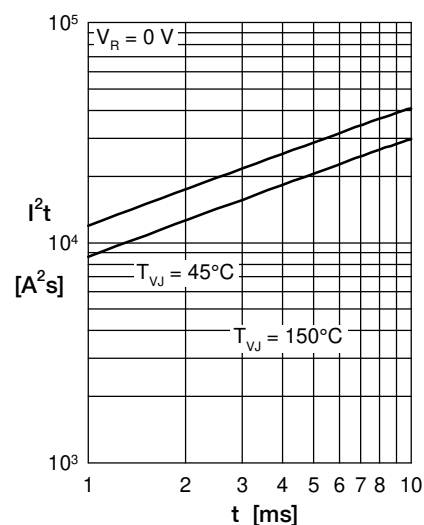
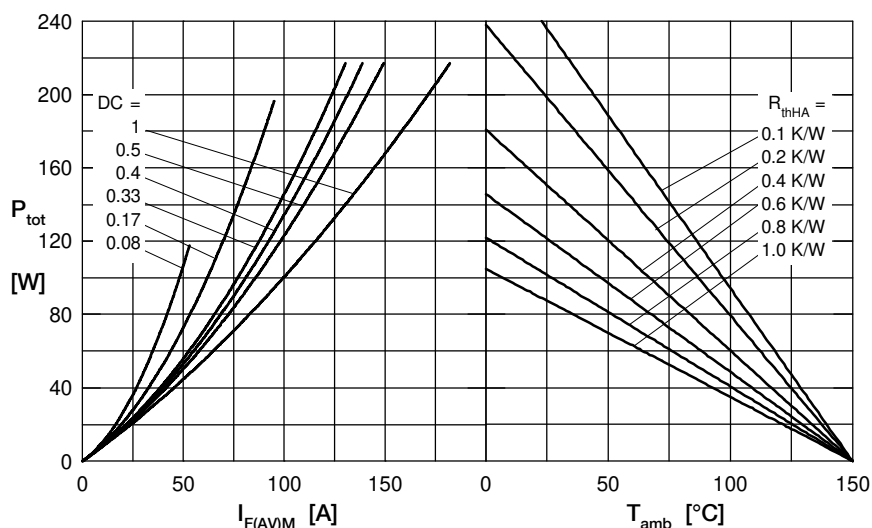

 Fig. 3  $I^2t$  versus time per diode


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

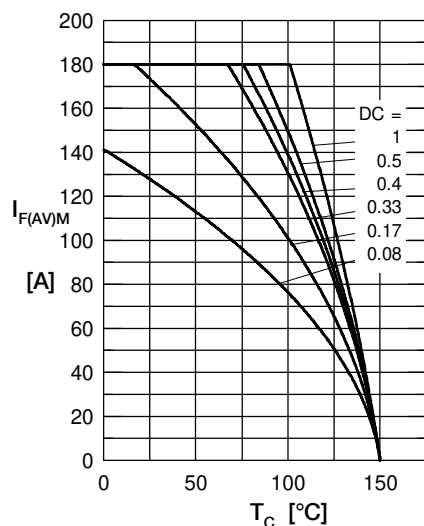


Fig. 5 Max. forward current vs. case temperature per diode

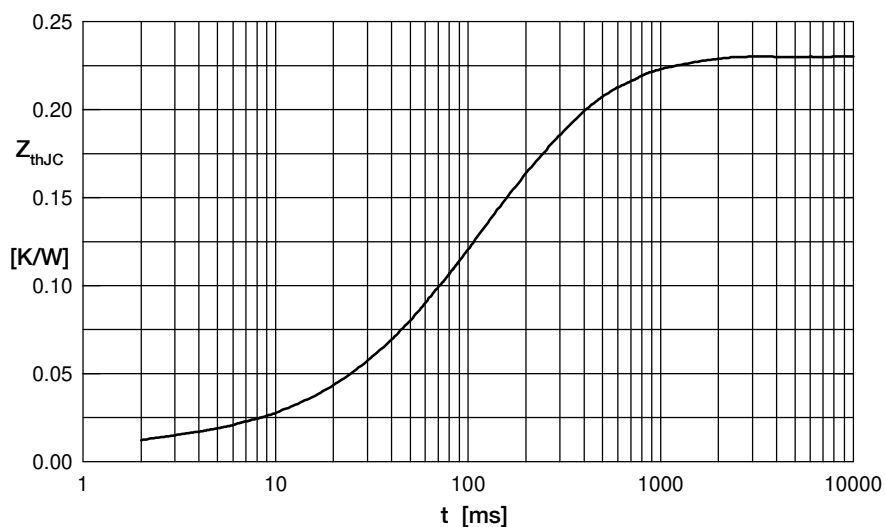


Fig. 6 Transient thermal impedance junction to case vs. time per diode

 Constants for  $Z_{thJC}$  calculation:

| i | $R_{thi}$ (K/W) | $t_i$ (s) |
|---|-----------------|-----------|
| 1 | 0.01            | 0.001     |
| 2 | 0.05            | 0.050     |
| 3 | 0.12            | 0.150     |
| 4 | 0.05            | 0.500     |